# Special Issue

# Challenges and Applications of Non-volatile Memory

## Message from the Guest Editor

The miniaturization of modern, cheaper electronics with a reduced power consumption is channelizing classical physics into the quantum domain. Among several others, non-volatile memories are one of the driving forces of this enormous development over the past few decades. This opens up new opportunities and applications of non-volatile memories to serve the future with a realistic view. In this Special Issue, we are particularly interested in high-quality submissions that highlight the current and future trends of flash memory; advances in emerging memory technologies, such as phase change memory, resistive random-access memory, ferroelectric memory, and so on; and emerging applications of non-volatile memories, addressing the recent breakthroughs in two-dimensional (2D) material systems for memory applications. The topics of interest include, but are not limited to, the following:

- Flash present and future
- Emerging nonvolatile memories
- Emerging devices and computing technology
- Emerging devices and security
- Non-volatile memories for biotechnology
- 2D materials and memory devices
- Failure analysis of non-volatile memories

Welcome to contribute.

## **Guest Editor**

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## Deadline for manuscript submissions

closed (31 October 2020)



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Electronics is a multidisciplinary journal designed to appeal to a diverse audience of research scientists, practitioners, and developers in academia and industry. The journal is devoted to fast publication of latest technological breakthroughs, cutting-edge developments, and timely reviews of current and emerging technologies related to the broad field of electronics. Experimental and theoretical results are published as regular peer-reviewed articles or as articles within Special Issues guestedited by leading experts in selected topics of interest.

## Editor-in-Chief

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